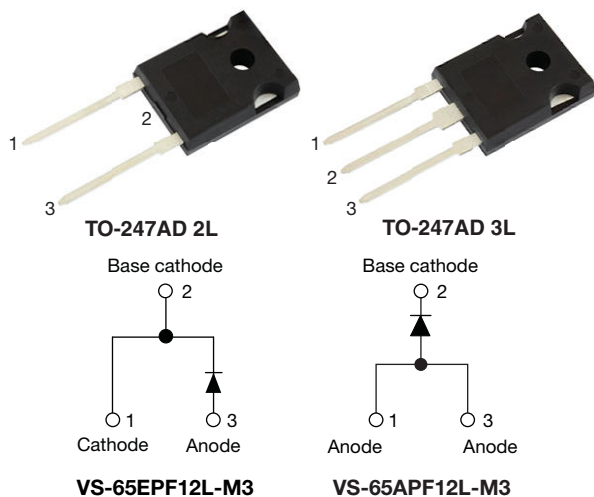


Fast Soft Recovery Rectifier Diode, 65 A



FEATURES

- Very low forward voltage drop and short reverse recovery time
- Glass passivated pellet chip junction
- Designed and qualified according to JEDEC®-JESD 47
- Flexible solution for reliable AC power rectification
- High surge, low V_F rugged blocking diode for DC charging stations
- AEC-Q101 qualified P/N available (VS-65EPF12LHM3, VS-65APF12LHM3)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

These devices are intended for use in output rectification and freewheeling in inverters, choppers and converters as well as in input rectification where severe restrictions on conducted EMI should be met.

DESCRIPTION

The VS-65EPF12L-M3, VS-65APF12L-M3 soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	65 A
V_R	1200 V
V_F at I_F	1.42 V
I_{FSM}	830 A
t_{rr}	95 ns
T_J max.	150 °C
Package	TO-247AD 2L, TO-247AD 3L
Circuit configuration	Single
Snap factor	0.6

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Sinusoidal waveform	65	A
V_{RRM}		1200	V
I_{FSM}		830	A
t_{rr}	1 A, 100 A/μs	95	ns
V_F	30 A, $T_J = 25$ °C	1.20	V
T_J		-40 to +150	°C

VOLTAGE RATINGS

PART NUMBER	V_{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 °C mA
VS-65EPF12L-M3	1200	1300	16
VS-65APF12L-M3	1200	1300	

**ABSOLUTE MAXIMUM RATINGS**

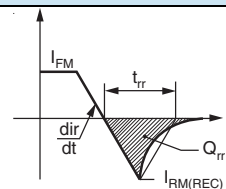
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 113\text{ }^{\circ}\text{C}$, 180° conduction half sine wave	65	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	700	
		10 ms sine pulse, no voltage reapplied	830	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	2450	A^2s
		10 ms sine pulse, no voltage reapplied	3460	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1\text{ ms to } 10\text{ ms}$, no voltage reapplied	34 600	$\text{A}^2\sqrt{\text{s}}$

ELECTRICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum forward voltage drop	V_{FM}	65 A, $T_J = 25\text{ }^{\circ}\text{C}$	1.42	V
Forward slope resistance	r_t	$T_J = 150\text{ }^{\circ}\text{C}$	4.6	$\text{m}\Omega$
Threshold voltage	$V_{F(TO)}$		0.9	V
Maximum reverse leakage current	I_{RM}	$T_J = 25\text{ }^{\circ}\text{C}$	0.1	mA
		$T_J = 150\text{ }^{\circ}\text{C}$	16	

RECOVERY CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	t_{rr}	I_F at 60 A _{pk} 25 A/ μs 25 $^{\circ}\text{C}$	480	ns
Reverse recovery current	I_{rr}		8	A
Reverse recovery charge	Q_{rr}		2.7	μC
Snap factor	S	Typical	0.6	

**THERMAL - MECHANICAL SPECIFICATIONS**

THERMAL MECHANICAL CHARACTERISTICS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.25	°C/W
Maximum thermal resistance, junction to ambient		R _{thJA}		40	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth, and greased	0.25	
Approximate weight				6	g
				0.21	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device			Case style TO-247AD 2L	65EPF12L	
			Case style TO-247AD 3L	65APF12L	

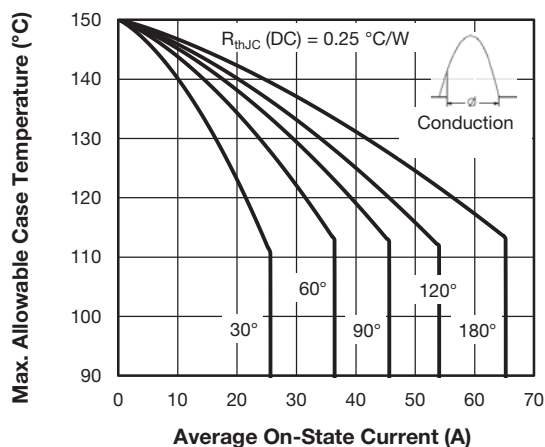


Fig. 1 - Current Rating Characteristics

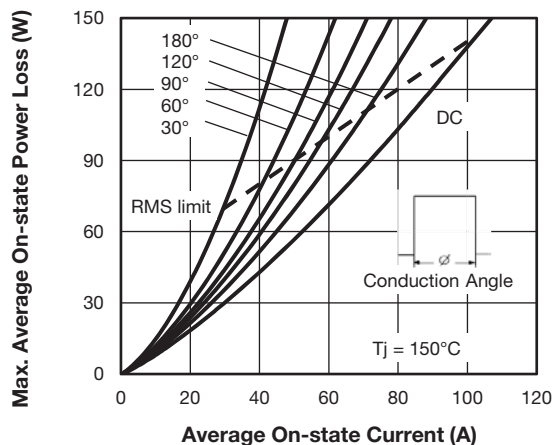


Fig. 4 - Forward Power Loss Characteristics

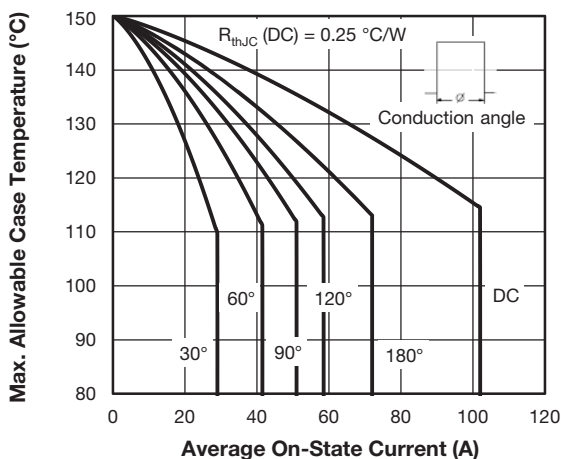


Fig. 2 - Current Rating Characteristics

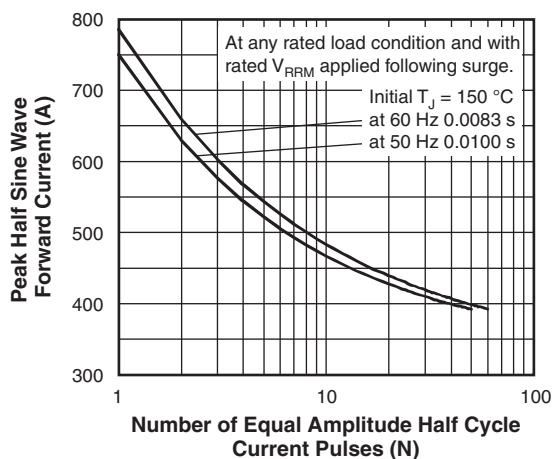


Fig. 5 - Maximum Non-Repetitive Surge Current

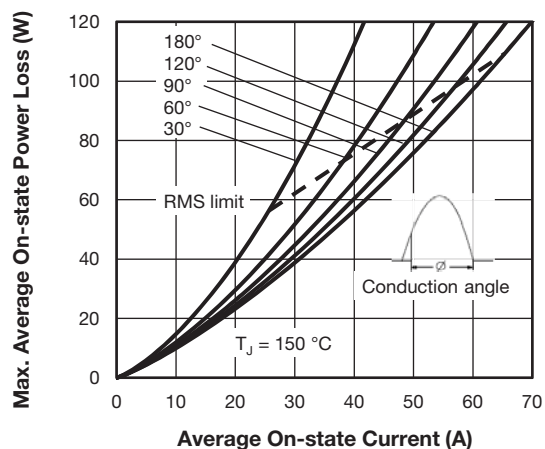


Fig. 3 - Forward Power Loss Characteristics

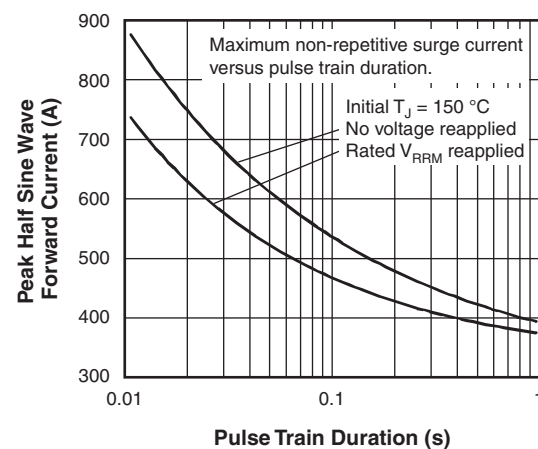


Fig. 6 - Maximum Non-Repetitive Surge Current

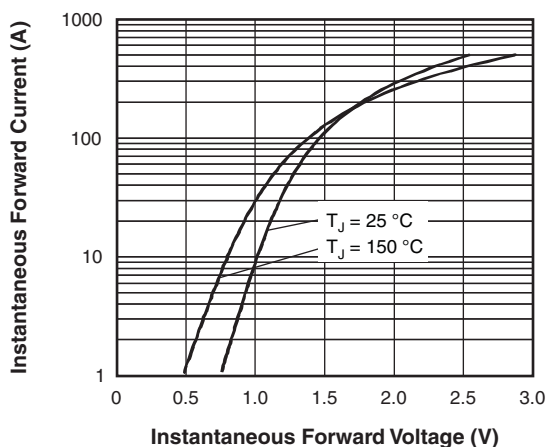
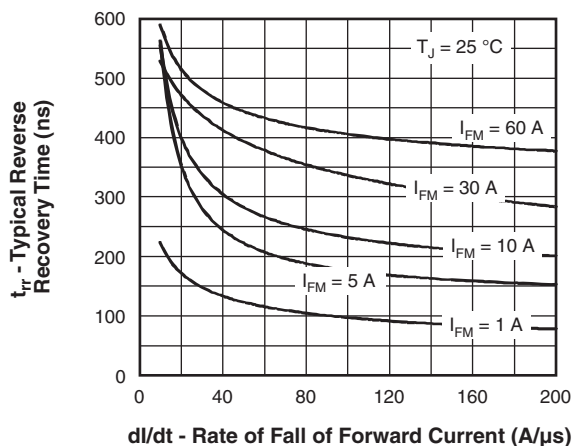
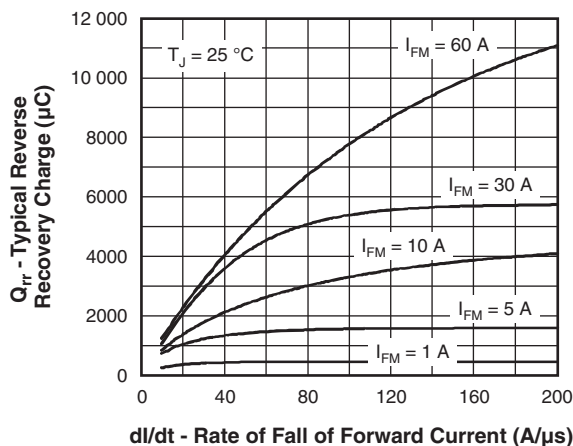
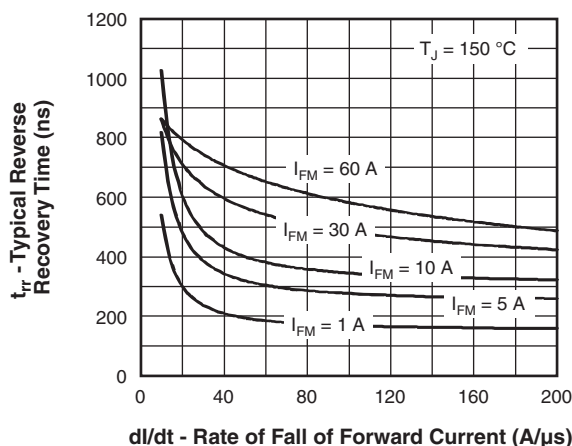
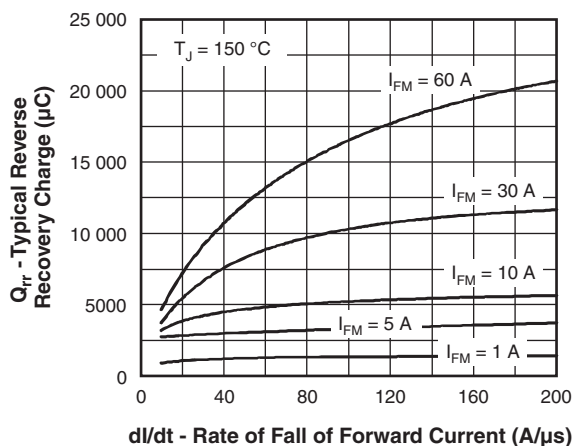


Fig. 7 - Forward Voltage Drop Characteristics


Fig. 8 - Recovery Time Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

Fig. 10 - Recovery Charge Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

Fig. 9 - Recovery Time Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

Fig. 11 - Recovery Charge Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

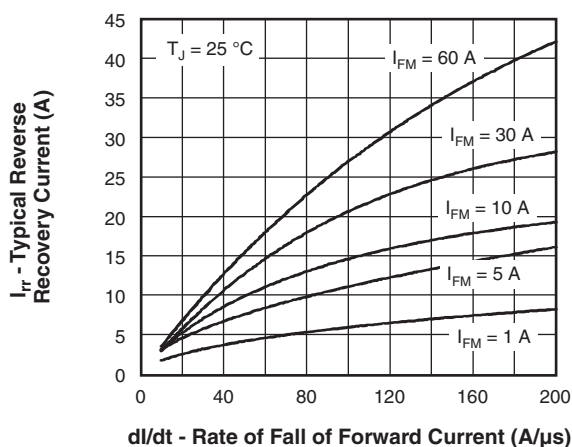


Fig. 12 - Recovery Current Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

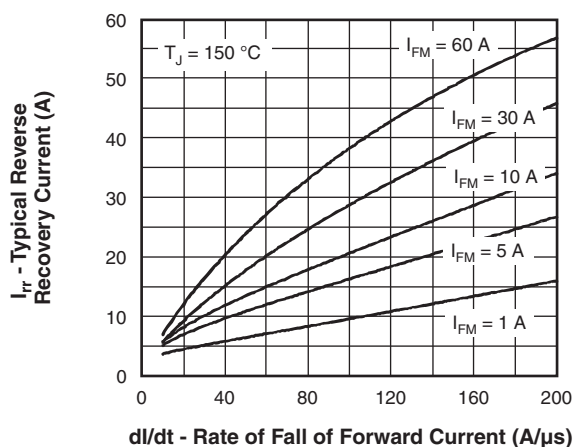


Fig. 13 - Recovery Current Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

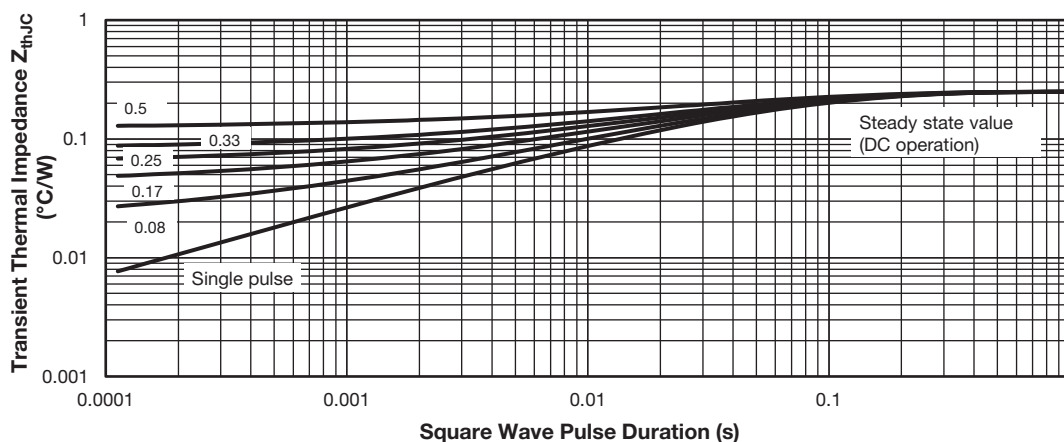


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

**ORDERING INFORMATION TABLE**

Device code

VS-	65	E	P	F	12	L	-M3
1	2	3	4	5	6	7	8

1

- Vishay Semiconductors product

2

- Current rating (65 = 65 A)

3

- Circuit configuration:

E = single, 2 pins

A = single, 3 pins

4

- Package:

P = TO-247AD

5

- Type of silicon:

F = fast recovery rectifier

6

- Voltage code x 100 = V_{RRM}

12 = 1200 V

7

- L = long leads

8

- Environmental digit:

-M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)

PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-65EPF12L-M3	25	500	Antistatic plastic tubes
VS-65APF12L-M3	25	500	Antistatic plastic tubes

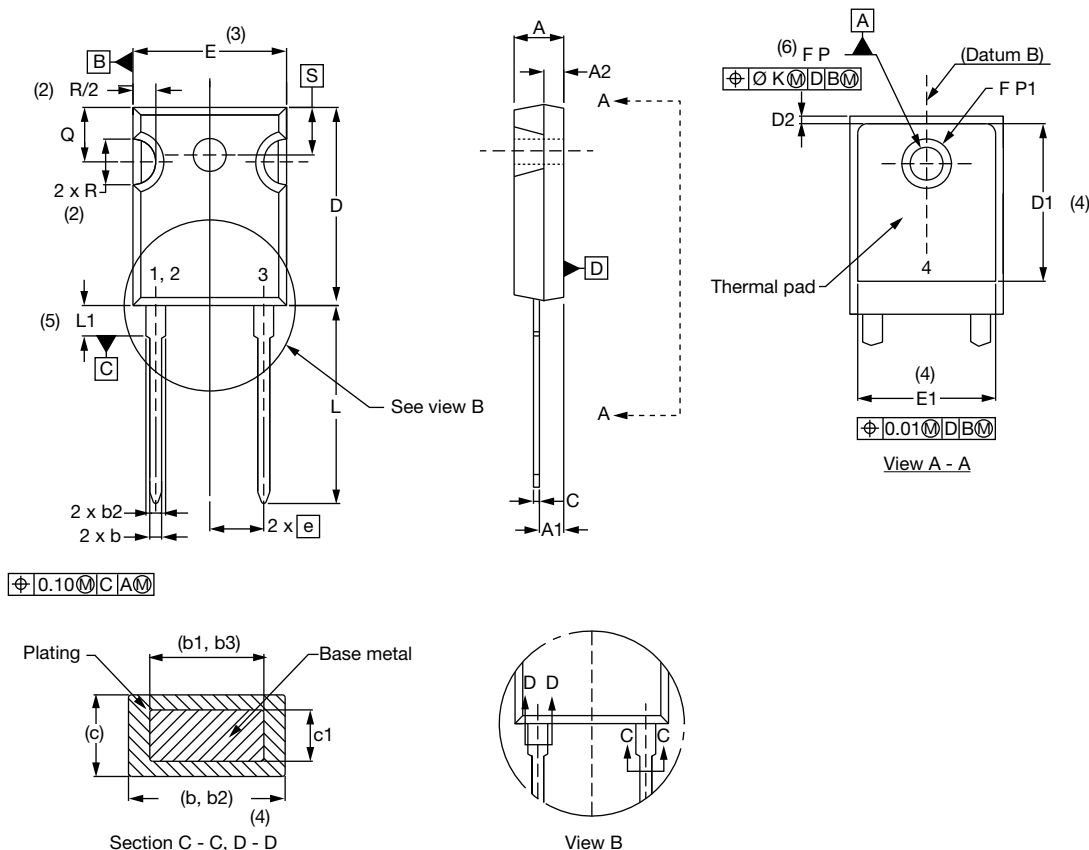
LINKS TO RELATED DOCUMENTS

Dimensions	TO-247AD 2L	www.vishay.com/doc?95536
	TO-247AD 3L	www.vishay.com/doc?95626
Part marking information	TO-247AD 2L	www.vishay.com/doc?95648
	TO-247AD 3L	www.vishay.com/doc?95007



TO-247AD 2L

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
A	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
c	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4
D2	0.51	1.35	0.020	0.053	

SYMBOL	MILLIMETERS		INCHES		NOTES
	MIN.	MAX.	MIN.	MAX.	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
e	5.46 BSC		0.215 BSC		
Ø K	0.254		0.010		
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
Ø P	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217 BSC		

Notes

- Dimensioning and tolerancing per ASME Y14.5M-1994
- Contour of slot optional
- Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- Thermal pad contour optional with dimensions D1 and E1
- Lead finish uncontrolled in L1
- Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- Outline conforms to JEDEC® outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4



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